PCS3P7303A





General Purpose Peak EMI Reduction IC

General Features

- 1x, LVCMOS Peak EMI Reduction
- Input frequency:

10MHz - 70MHz @ 2.5V

10MHz - 80MHz @ 3.3V

• Output frequency:

10MHz - 70MHz @ 2.5V

10MHz - 80MHz @ 3.3V

- Analog Deviation Selection
- ModRate selection option
- Supply Voltage: 2.5V ± 0.2V

 $3.3V \pm 0.3V$

- 8-pin TSSOP, 8L 2mmX2mm WDFN(TDFN) Packages
- The First True Drop-in Solution

Functional Description

PCS3P7303A is a versatile, 3.3V/2.5V Peak EMI reduction IC based on Timing-Safe™ technology. PCS3P7303A accepts an input clock either from a Crystal or from an external reference (AC or DC coupled to XIN / CLKIN) and

locks on to it delivering a 1x modulated clock output. PCS3P7303A has a Frequency Selection (FS) control that facilitates selecting one of the two frequency ranges within the operating frequency range. Refer to the *Frequency Selection* Table for details.

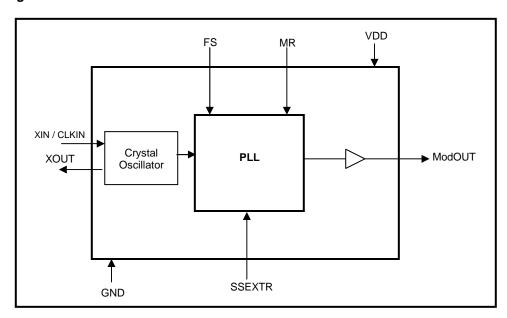
PCS3P7303A has an SSEXTR pin to select different deviations depending upon the value of an external resistor connected between SSEXTR and GND. Modulation Rate (MR) control selects two different Modulation Rates.

PCS3P7303A operates from a 3.3V/2.5V supply and is available in an 8-pin TSSOP and 8L 2mmX2mm WDFN packages.

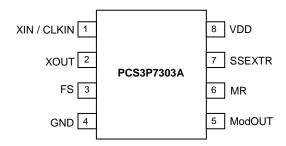
Application

PCS3P7303A is targeted for many applications including USB and SATA.

Block Diagram



Pin Configuration



Pin Description

Pin#	Pin Name	Pin Type	Description
1	XIN / CLKIN	I	Crystal connection or External reference clock input.
2	XOUT	0	Crystal connection. If using an external reference, this pin should be left open.
3	FS	I	Frequency Select. Pull LOW to select Low Frequency range. Selects High Frequency range when pulled HIGH. Has an internal pull-up resistor. (See <i>Frequency Selection table</i> for details.)
4	GND	Р	Ground.
5	ModOUT	0	Buffered Modulated clock output.
6	MR	1	Modulation Rate Select. When LOW selects Low Modulation Rate. Selects High Modulation Rate when pulled HIGH. Has an internal pull-down resistor.
7	SSEXTR	Ī	Analog Deviation Selection through external resistor to GND.
8	VDD	Р	2.5V / 3.3V supply Voltage.

Frequency Selection Table

VDD (V)	FS	Frequency (MHz)
	0	10-35
2.5	1	30-70
	0	10-40
3.3	1	30-80

Absolute Maximum Rating

Symbol	Parameter	Rating	Unit			
VDD, V _{IN}	Voltage on any input pin with respect to Ground	-0.5 to +4.6	V			
T _{STG}	Storage temperature	-65 to +125	Ç			
Ts	Max. Soldering Temperature (10 sec)	260	Ç			
TJ	Junction Temperature	150	\mathcal{L}			
T_DV	Static Discharge Voltage (As per JEDEC STD22- A114-B)	2	KV			
Note: These are stress ratings only and are not implied for functional use. Exposure to absolute maximum ratings for prolonged periods of time may affect device reliability.						

Operating Conditions

Parameter	Description	Min	Max	Unit
VDD	Supply Voltage	2.3	3.6	V
T_A	Operating Temperature (Ambient Temperature)	-25	+85	C
C_L	Load Capacitance		10	pF
C _{IN}	Input Capacitance		7	pF

DC Electrical Characteristics for 2.5V

Parameter	Description	Test C	Test Conditions		Тур	Max	Unit
VDD	Supply Voltage			2.3	2.5	2.7	V
V_{IL}	Input LOW Voltage					0.7	V
V _{IH}	Input HIGH Voltage			1.7			V
I _{IL}	Input LOW Current	$V_{IN} = 0V$	V _{IN} = 0V			-50	μA
I _{IH}	Input HIGH Current	$V_{IN} = V_{DD}$				50	μΑ
V_{OL}	Output LOW Voltage	$I_{OL} = 8mA$	I _{OL} = 8mA			0.6	V
V_{OH}	Output HIGH Voltage	$I_{OH} = -8mA$	I _{OH} = -8mA				V
I _{cc}	Static Supply Current	XIN / CLKIN pulle	d low			500	μA
			FS=0; @ 10MHz			5	
I _{DD}	Dynamic Supply Current	Unloaded Output	FS=1; @ 70MHz			12	mA
Z _o	Output Impedance				45		Ω

Switching Characteristics for 2.5V

Parameter	Tes	Test Conditions			Тур	Max	Unit
Input Frequency ¹ /	FS=0	FS=0				35	
ModoUT	FS=1			30		70	MHz
Duty Cycle ^{2, 3}	Measured at V _{DD} /2			45	50	55	%
Output Rise Time 2,3	Measured between 20	Measured between 20% to 80%			1.75	2.5	nS
Output Fall Time ^{2,3}	Measured between 80	Measured between 80% to 20%			1.0	1.6	nS
			10MHz		±450	±600	pS
3		FS=0	35MHz		±125	±250	
Cycle-to-Cycle Jitter ³	Unloaded output		30MHz		±225	±350	
	·	FS=1 70MHz			±150	±300	
3	Stable power supply,	Stable power supply, valid clock presented on XIN / CLKIN					0
PLL Lock Time ³	CLKIN					3	mS

Notes: 1. Functionality with Crystal is guaranteed by design and characterization. Not 100% tested in production.

2. All parameters are specified with 10pF loaded outputs.

3. Parameter is guaranteed by design and characterization. Not 100% tested in production.

DC Electrical Characteristics for 3.3V

Parameter	Description	Test Conditions		Min	Тур	Max	Unit
VDD	Supply Voltage			3.0	3.3	3.6	V
V_{IL}	Input LOW Voltage					0.8	V
V _{IH}	Input HIGH Voltage			2.0			V
I _{IL}	Input LOW Current	$V_{IN} = 0V$				-50	μΑ
I _{IH}	Input HIGH Current	$V_{IN} = V_{DD}$				50	μΑ
V_{OL}	Output LOW Voltage	I _{OL} = 8mA				0.4	V
V_{OH}	Output HIGH Voltage	$I_{OH} = -8mA$		2.4			V
I _{CC}	Static Supply Current	XIN / CLKIN pulle	ed low			700	μΑ
			FS=0; @ 10MHz			7	
I _{DD}	Dynamic Supply Current	Unloaded Output FS=1; @ 80MHz				20	mA
Z _o	Output Impedance				35		Ω

Switching Characteristics for 3.3V

Parameter	Test Conditions			Min	Тур	Max	Unit
1/1/10/17	FS=0			10		40	
Input Frequency ¹ / ModOUT	FS=1			30		80	MHz
Duty Cycle ^{2, 3}	Measured at V _{DD} /2			45	50	55	%
Output Rise Time 2,3	Measured between 20% to 80%				1.3	2	nS
Output Fall Time 2,3	Measured between 80% to 20%				0.9	1.3	nS
	Unloaded output	FS=0	10MHz		±450	±600	
3			40MHz		±125	±250	pS
Cycle-to-Cycle Jitter ³		50 4	30MHz		±225	±350	
	FS=1 80MHz			±125	±250		
PLL Lock Time ³	Stable power supply, valid clock presented on XIN / CLKIN					3	mS

Notes: 1. Functionality with Crystal is guaranteed by design and characterization. Not 100% tested in production.

2. All parameters are specified with10pF loaded outputs.

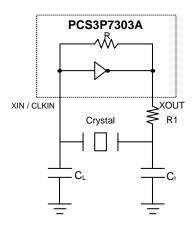
3. Parameter is guaranteed by design and characterization. Not 100% tested in production.

Typical Crystal Specifications

Fundamental AT cut parallel resonant crystal				
Nominal frequency	25MHz			
Frequency tolerance	±50ppm or better at 25℃			
Operating temperature range	-25℃ to +85℃			
Storage temperature	-40℃ to +85℃			
Load capacitance(C _P)	18pF			
Shunt capacitance	7pF maximum			
ESR	25 Ω			

Note: C_L is the Load Capacitance and R1 is used to prevent oscillations at overtone frequency of the Fundamental frequency.

Typical Crystal Interface Circuit

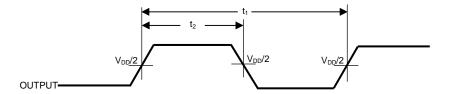


 $C_L = 2^*(C_P - C_S),$

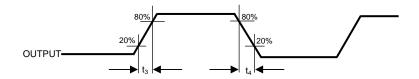
Where C_P = Load capacitance of crystal from crystal vendor datasheet. C_S = Stray capacitance due to C_{IN} , PCB, Trace, etc.

Switching Waveforms

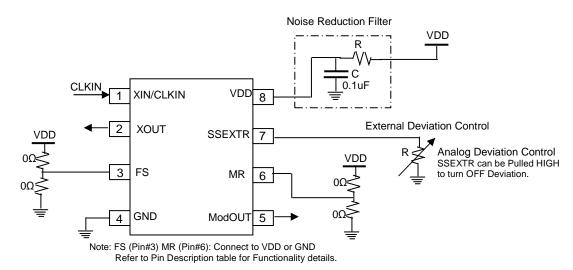
Duty Cycle Timing



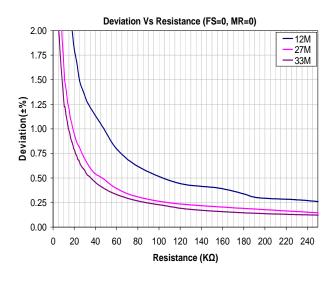
Output Rise/Fall Time

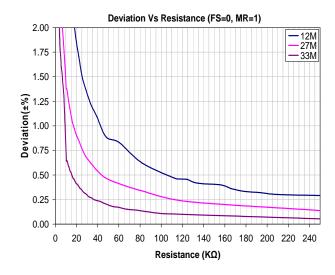


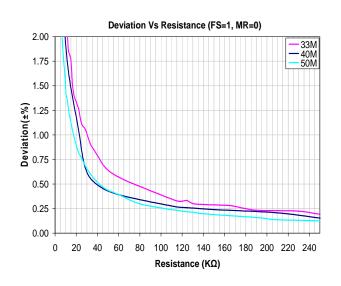
Application Schematic

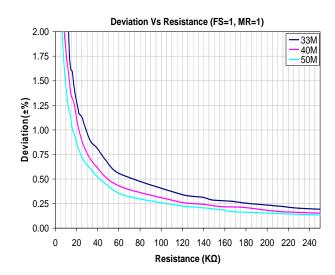


Charts





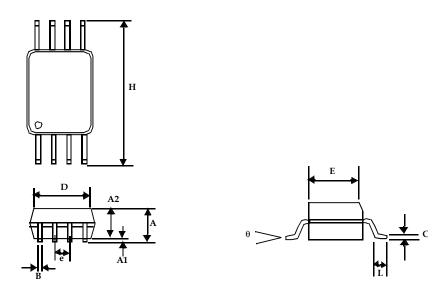




Note: Device to Device variation of Deviation is $\pm 10\%$ (0% to +70%) and $\pm 25\%$ (-25% to +85%)

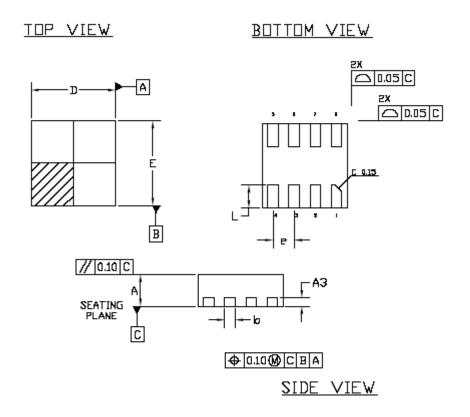
Package Information

8-lead TSSOP Package (4.40-MM Body)



	Dimensions						
Symbol	Inc	hes	Millimeters				
	Min	Max	Min	Max			
А		0.043		1.10			
A1	0.002	0.006	0.05	0.15			
A2	0.033	0.037	0.85	0.95			
В	0.008	0.012	0.19	0.30			
С	0.004	0.008	0.09	0.20			
D	0.114	0.122	2.90	3.10			
Е	0.169	0.177	4.30	4.50			
е	0.026	BSC	0.65	BSC			
Н	0.252	BSC	6.40) BSC			
L	0.020	0.028	0.50	0.70			
θ	0°	8°	0°	8°			

8L 2mmX2mm WDFN package Outline drawing



	Dimensions					
Symbol	Inch	nes	Milli	imeters		
	Min	Max	Min	Max		
Α	0.027	0.0315	0.70	0.80		
А3	0.008	BSC	0.203 BSC			
b	0.008	0.012	0.20	0.30		
D	0.079	BSC	2.0	00 BSC		
Е	0.078 BSC		2.00 BSC			
е	0.020 BSC		0.5	0 BSC		
L	0.020	0.024	0.50	0.60		

Ordering Code

Part Number	Marking	Package	Temperature
PCS3P7303AG-08TR	BKL	8-pin TSSOP, TAPE AND REEL, Green	-25℃ to +85℃
PCS3P7303AG-08TT	BKL	8-pin TSSOP, TUBE, Green	-25℃ to +85℃
PCS3P7303AG-08CR	BK	8L WDFN (2mmX2mm), TAPE & REEL, Green	-25℃ to +85℃

A "microdot" placed at the end of last row of marking or just below the last row toward the center of package indicates Pb-free.

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